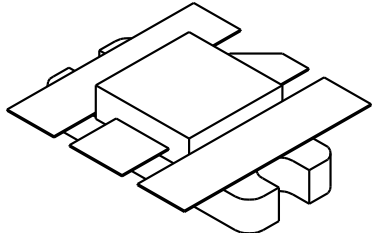


UMIL 100A

100 Watts, 28 Volts, Class AB
Defcom 225 - 400 MHz

<p>GENERAL DESCRIPTION</p> <p>The UMIL100A is a double input matched COMMON EMITTER broadband transistor specifically intended for use in the 225-400 MHz frequency band. It may be operated in Class AB or C. Gold metallization and silicon diffused resistors ensure ruggedness and high reliability.</p>	<p>CASE OUTLINE 55JU, Style 2</p> 
<p>ABSOLUTE MAXIMUM RATINGS</p> <p>Maximum Power Dissipation @ 25°C 270 Watts</p> <p>Maximum Voltage and Current</p> <p>BVces Collector to Emitter Voltage 65 Volts BVebo Emitter to Base Voltage 4.0 Volts Ic Collector Current 20 A</p> <p>Maximum Temperatures</p> <p>Storage Temperature - 65 to +150°C Operating Junction Temperature +150°C</p>	

ELECTRICAL CHARACTERISTICS @ 25 °C

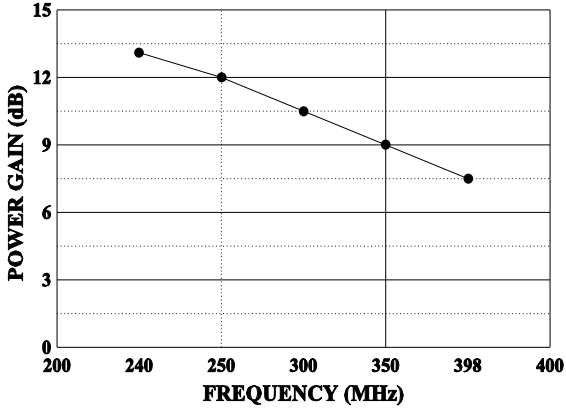
SYMBOL	CHARACTERISTICS	TEST CONDITIONS	MIN	TYP	MAX	UNITS
Pout	Power Output	F = 400 MHz	100			Watts
Pin	Power Input	Vcc = 28 Volts			19	Watts
Pg	Power Gain		7.2	8.5		dB
η_c	Efficiency			55		%
VSWR	Load Mismatch Tolerance				5:1	

BVebo	Emitter to Base Breakdown	Ie = 5 mA	4.0			Volts
BVces	Collector to Emitter Breakdown	Ic = 100 mA	60			Volts
BVceo	Collector to Emitter Breakdown	Ie = 50 mA	31			Volts
BVcbo	Collector to Base Breakdown	Ic = 100 mA	60			Volts
Icbo	Collector to Base Current	Vc = 30 Volts			50	mA
Cob	Output Capacitance	Vcb = 28 V, F = 1 MHz		120		pF
hFE	DC - Current Gain	Vce = 5 V, Ic = 1 A	10			
θ_{jc}	Thermal Resistance				0.7	°C/W

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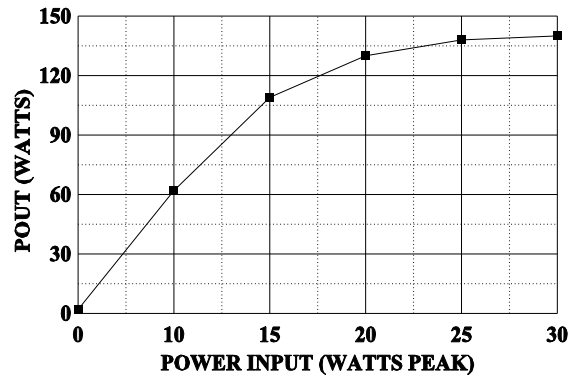
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POWER GAIN VS FREQUENCY



POWER OUTPUT vs POWER INPUT

$V_{cc} = 28V$ $f = 400MHz$



DC SAFE OPERATING AREA

